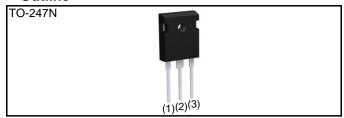


### **Automotive Grade N-channel SiC power MOSFET**

$V_{DSS}$	650V
$R_{DS(on)}$ (Typ.)	60mΩ
I <sub>D</sub> *1	39A
$P_D$	165W

#### Outline

●Inner circuit



(2)

(3)

(1) Gate

(2) Drain (3) Source

\*Body Diode

#### Features

- 1) Qualified to AEC-Q101
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Fast reverse recovery
- 5) Easy to parallel
- 6) Simple to drive
- 7) Pb-free lead plating; RoHS compliant

#### Application

- Automobile
- Switch mode power supplies

#### Packaging specifications

,	ging opcomouncing	
	Packing	Tube
	Reel size (mm)	-
Turo	Tape width (mm)	-
Type	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT3060AL

## ● **Absolute maximum ratings** (T<sub>vj</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source Voltage		$V_{DSS}$	650	V
Continuous Drain current	T <sub>c</sub> = 25°C	I <sub>D</sub> *1	39	А
Continuous Drain current	T <sub>c</sub> = 100°C	I <sub>D</sub> *1	27	А
Pulsed Drain current (T <sub>c</sub> = 25°C)		I <sub>D,pulse</sub> *2	97	А
Gate - Source voltage (DC)		$V_{GSS}$	-4 to +22	V
Gate - Source surge voltage (t <sub>surge</sub> < 300nsec)		V <sub>GSS_surge</sub> *3	-4 to +26	V
Recommended drive voltage		$V_{GS\_op}^{*4}$	0 / +18	V
Virtual Junction temperature		$T_{vj}$	175	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +175	°C

## ullet Electrical characteristics ( $T_{vj} = 25^{\circ}C$ unless otherwise specified)

Doromotor	Symbol	Conditions Min.		Values		
Parameter	Symbol		Min.	Тур.	Max.	Unit
		$V_{GS} = 0V$ , $I_D = 1mA$				
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$T_{vj} = 25^{\circ}C$	650	-	-	V
renage		T <sub>vj</sub> = -55°C	650	-	-	
		$V_{GS} = 0V, V_{DS} = 650V$				
Zero Gate voltage Drain current	I <sub>DSS</sub>	$T_{vj} = 25^{\circ}C$	-	1	10	μΑ
Drain Garrein		$T_{vj} = 150$ °C	-	2	-	
Gate - Source leakage current	I <sub>GSS+</sub>	$V_{GS} = +22V$ , $V_{DS} = 0V$	-	-	100	nA
Gate - Source leakage current	I <sub>GSS-</sub>	$V_{GS} = -4V$ , $V_{DS} = 0V$	-	-	-100	nA
Gate threshold voltage	V <sub>GS (th)</sub>	$V_{DS} = 10V, I_{D} = 6.67 \text{mA}$	2.7		5.6	V
		$V_{GS} = 18V, I_D = 13A$				
Static Drain - Source on - state resistance	R <sub>DS(on)</sub> *5	$T_{vj} = 25^{\circ}C$	-	60	78	mΩ
2 2		T <sub>vj</sub> = 150°C	-	86	-	
Gate input resistance	$R_{G}$	f = 1MHz, open drain	-	12	-	Ω

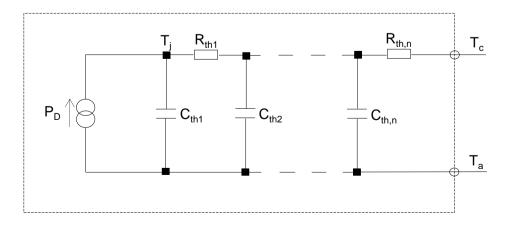
#### ●Thermal resistance

Parameter	Symbol	Values			Unit
raianietei		Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	$R_{thJC}$	-	0.70	0.91	K/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R <sub>th1</sub>	9.00E-02	
R <sub>th2</sub>	5.96E-01	K/W
R <sub>th3</sub>	1.47E-02	

Symbol	Value	Unit
C <sub>th1</sub>	1.23E-03	
$C_{th2}$	7.32E-03	Ws/K
$C_{th3}$	1.64E-01	



# ullet Electrical characteristics ( $T_{vj} = 25^{\circ}C$ unless otherwise specified)

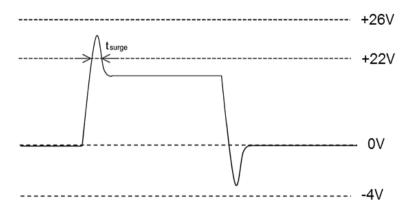
Doromotor	Cymphol	Conditions		Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	<b>g</b> fs *5	$V_{DS} = 10V, I_{D} = 13A$	-	4.9	-	S
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	852	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 500V	-	55	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	24	-	
Effective output capacitance, energy related	C <sub>o(er)</sub>	$V_{GS} = 0V$ $V_{DS} = 0V \text{ to } 300V$	-	126	-	pF
Total Gate charge	Qg *5	$V_{DS} = 300V$ $I_{D} = 13A$	-	58	-	
Gate - Source charge	Q <sub>gs</sub> *5	V <sub>GS</sub> = 18V	-	11	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5	See Fig. 1-1.	-	31	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DS} = 300V$ $I_{D} = 13A$	-	19	-	
Rise time	t <sub>r</sub> *5	$V_{GS} = 0V/+18V$	-	37	-	ne
Turn - off delay time	t <sub>d(off)</sub> *5	$R_G = 0\Omega$ $R_L = 23\Omega$	-	34	-	ns
Fall time	t <sub>f</sub> *5	See Fig. 1-1, 1-2.	-	21	-	
Turn - on switching loss	E <sub>on</sub> *5	$V_{DS} = 300V$ $V_{GS} = 0V/18V$ , $I_{D} = 13A$ $R_{G} = 0\Omega$ , $L = 500\mu H$	-	70	-	,, 1
Turn - off switching loss	E <sub>off</sub> *5	$E_{on}$ includes diode reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 2-1, 2-2.	-	10	-	μJ

## ullet Body diode electrical characteristics (Source-Drain) ( $T_{vj} = 25^{\circ}$ C unless otherwise specified)

Parameter	Symbol	Conditions		Values		
r arameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Body diode continuous, forward current	I <sub>S</sub> *1	T <sub>c</sub> = 25°C	1	1	39	А
Body diode direct current, pulsed	I <sub>SM</sub> *2	11 <sub>c</sub> = 23 0	ı	ı	97	А
Forward voltage	V <sub>SD</sub> *5	$V_{GS} = 0V, I_{S} = 13A$	ı	3.2		V
Reverse recovery time	t <sub>rr</sub> *5	$I_F = 13A$ $V_R = 300V$	-	15	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 1100A/μs	-	55	-	nC
Peak reverse recovery current	I <sub>rrm</sub> *5	$L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 3-1, 3-2.	-	8	-	А

<sup>\*1</sup> Limited by maximum  $T_{\nu j}$  and for Max.  $R_{thJC}.$ 

## \*3 Example of acceptable $V_{\text{GS}}$ waveform



\*5 Pulsed

<sup>\*2</sup> PW  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

 $<sup>^{*}4</sup>$  Please be advised not to use SiC-MOSFETs with  $V_{GS}$  below 13V as doing so may cause thermal runaway.

Fig.1 Power Dissipation Derating Curve

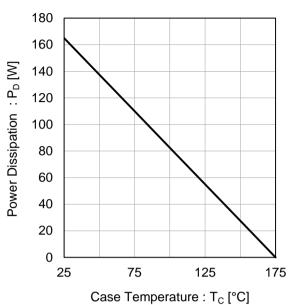


Fig.2 Maximum Safe Operating Area

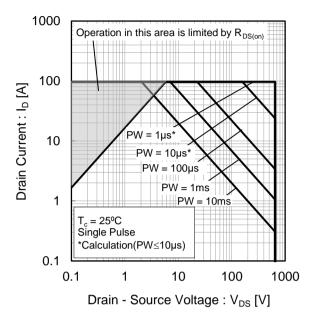
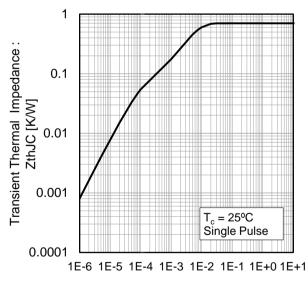


Fig.3 Typical Transient Thermal Resistance vs. Pulse Width



Pulse Width: PW [s]

Fig.4 Typical Output Characteristics(I)

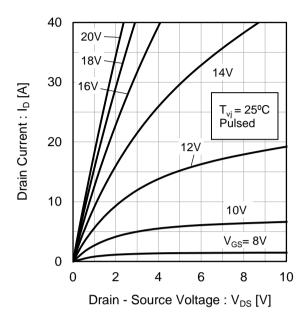


Fig.5 Typical Output Characteristics(II)

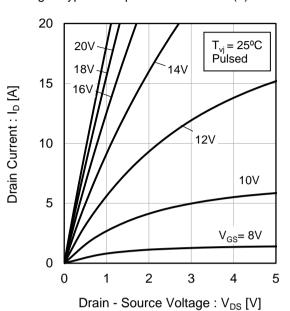
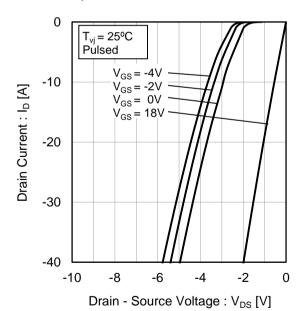
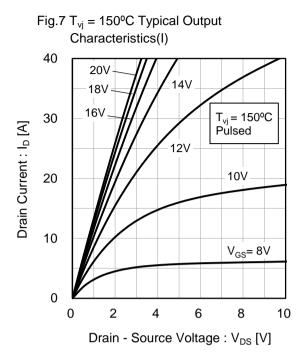
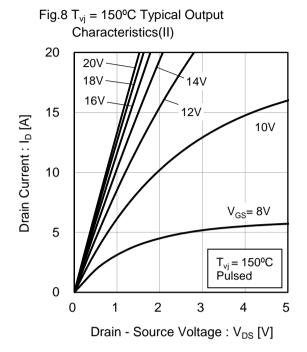


Fig.6 T<sub>vj</sub> = 25°C 3rd Quadrant Characteristics

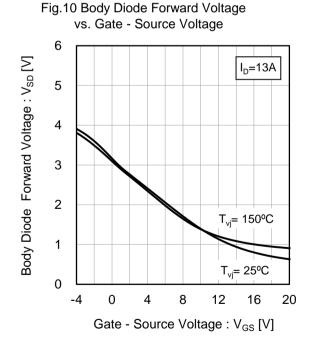






Characteristics  $T_{vj} = 150^{\circ}C$ Pulsed  $V_{GS} = -4V$ -10 Drain Current: I<sub>D</sub> [A]  $V_{GS}^{GS} = -2V$  $V_{GS} = 0V$   $V_{GS} = 18V$ -20 -30 -40 -10 -8 -6 0 Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.9 T<sub>vj</sub> = 150°C 3rd Quadrant



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Fig.11 Typical Transfer Characteristics (I)

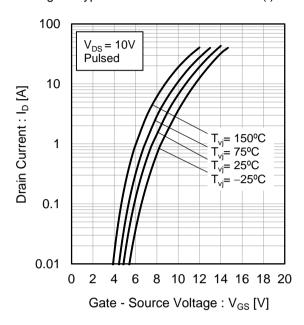


Fig.12 Typical Transfer Characteristics (II)

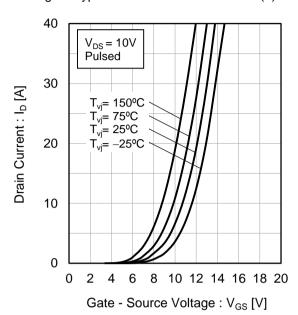


Fig.13 Gate Threshold Voltage vs. Junction Temperature

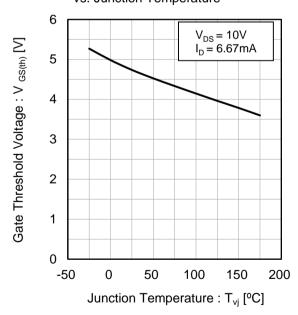
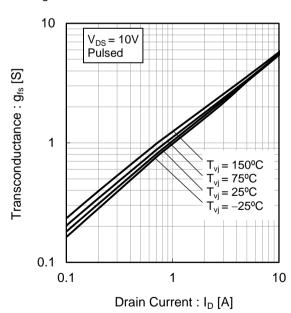


Fig.14 Transconductance vs. Drain Current



Resistance vs. Gate - Source Voltage 0.24  $T_{vi} = 25^{\circ}C$ Pulsed Static Drain - Source On-State 0.20 I<sub>D</sub>= 26A Resistance :  $R_{DS(on)}[\Omega]$ 0.16 I<sub>D</sub>= 13A 0.12 0.08 I<sub>D</sub>= -13A 0.04 0.00 20 22 8 10 12 14 16 18 Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.15 Static Drain - Source On - State

Resistance vs. Junction Temperature 0.12  $V_{GS} = 18V$ Pulsed Static Drain - Source On-State Resistance :  $R_{DS(on)}$  [ $\Omega$ ] 0.0 0.0 80 I<sub>D</sub>= 26A I<sub>D</sub>= 13A  $I_{D} = -13A$ 0.00 -50 0 100 200 50 150 Junction Temperature : T<sub>vi</sub> [°C]

Fig.16 Static Drain - Source On - State

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current 1 Static Drain - Source On-State Resistance:  $R_{DS(on)}[\Omega]$ 0.1 <sub>vj</sub> = 150°C  $T_{vj} = 125^{\circ}C$  $T_{vj}^{vj} = 75^{\circ}C$ , vj = 25°C  $V_{GS} = 18V$  $T_{vj} = -25^{\circ}C$ 0.01 10 100 Drain Current: I<sub>D</sub> [A]

Voltage vs. Junction Temperature

1.04

1.03

1.03

1.00

1.01

1.00

1.01

1.00

0.99

0.98

-50

0

Junction Temperature : T<sub>vj</sub> [°C]

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Fig.18 Normalized Drain - Source Breakdown

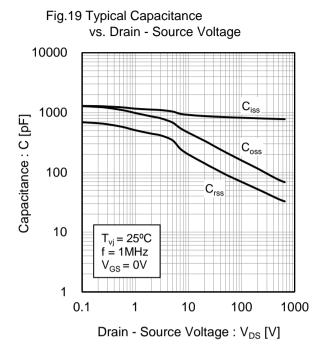
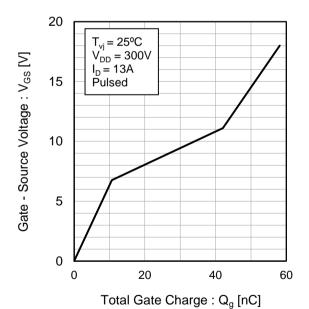


Fig.21 Dynamic Input Characteristics



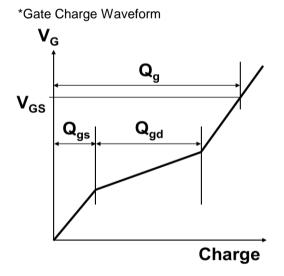


Fig.19 Typical Switching Time vs. Drain Current

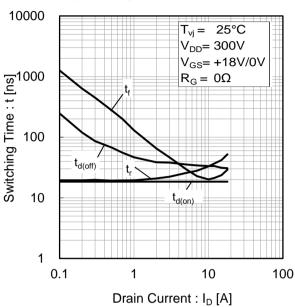


Fig.20 Typical Switching Loss vs. Drain - Source Voltage

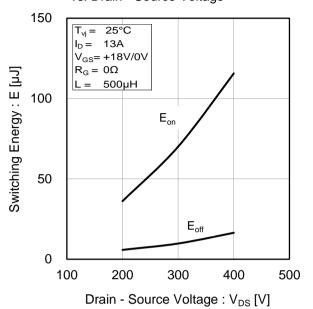


Fig.21 Typical Switching Loss vs. Drain Current

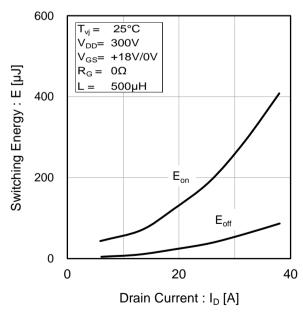
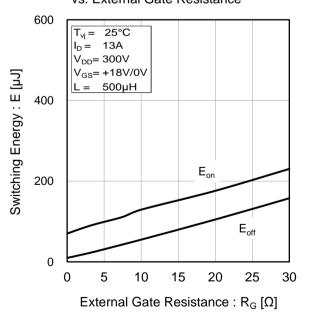


Fig.22 Typical Switching Loss vs. External Gate Resistance



#### Measurement circuits and waveforms

Fig.1-1 Gate Charge and Switching Time Measurement Circuit

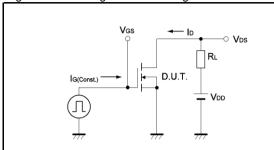


Fig.2-1 Switching Energy Measurement Circuit

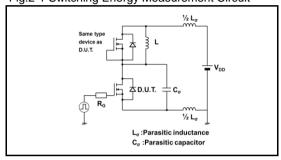


Fig.3-1 Reverse Recovery Time Measurement Circuit

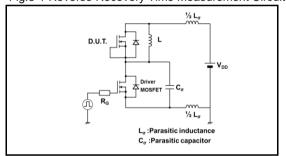


Fig.1-2 Waveforms for Switching Time

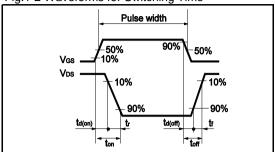


Fig.2-2 Waveforms for Switching Energy Loss

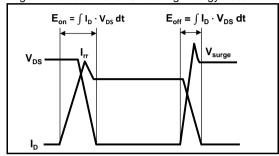
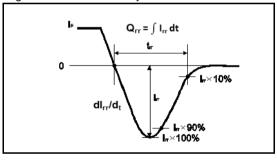
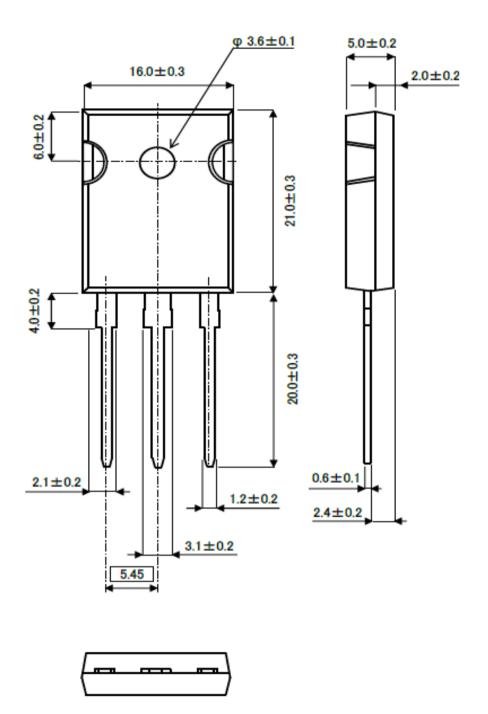


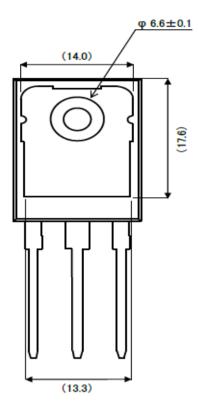
Fig.3-2 Reverse Recovery Waveform



### ●Package Dimensions

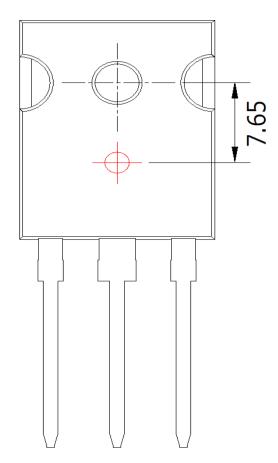


Unit: mm



Unit: mm

### ●Die Bonding Layout





- •Front view of the packaging.
- •Dimensions are design values.
- ·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm

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